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PRESSURELESS SINTERED β' -Si₃N₄ SOLID SOLUTION: FABRICATION, MICROSTRUCTURE, AND STRENGTH

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PRESSURELESS SINTERED β -Si₃N₄ \mathfrak{D} LID SOLUTION: FABRICATION, MICROSTRUCTURE, AND STRENGTH by Sunil Dutta

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SUMMARY

Pressureless sintering of β^{r} -Si $_{3}$ N $_{4}$ solid solution was studied as a function of temperature using Si $_{3}$ N $_{4}$, AlN, and Al $_{2}$ O $_{3}$ as basic constituents. Y $_{2}$ O $_{3}$ -SiO $_{2}$ additions were used to promote liquid-phase sintering. The sintered specimens were characterized with respect to density, microstructure, strength, oxidation, and thermal shock resistance. Density greater than 98 percent of theoretical was achieved by pressureless sintering at 1750 0 C. The microstructure consisted essentially of fine-grained β^{r} -Si $_{3}$ N $_{4}$ solid solution as the major phase. Modulus of rupture strengths up to 483 MPa were achieved at moderate temperature (1000 0 C), but decreased to 228 MPa at 1380 0 C. This substantial strength loss was attributed to a "glassy" grain boundary phase formed during cooling from the sintering temperature. The best oxidation resistance was exhibited by a composition containing 3 mol % Y $_{2}$ O $_{3}$ -SiO $_{2}$ additives. Water quench thermal shock resistance was equivalent to that of reaction sintered silicon nitride but lower than hotpressed silicon nitride.

While work in pressureless sintering is still in the early stages, the results of strength, oxidation, and thermal shock tests are extremely—couraging and suggest that with further development, it will be possible by pressureless sintering to produce dense, high strength β -Si₃N₄ solid solution bodies for high-temperature structural applications.

INTRODUCTION

The existence of β '-Si $_3$ N $_4$ solid solution in the system Si $_3$ N $_4$ -Al $_2$ O $_3$ was first reported by Oyama and Kamigaito 1 in Japan and by Jack and Wilson 2 : England. Subsequent studies 3 , 4 found that Si $_3$ N $_4$ -Al $_2$ O $_3$ mixtures do not form a single

phase β -Si₃N₄ solid solution for any composition. Instead, β -Si₃N₄ forms along the join Si₃N₄ and AlN-Al₂O₃ in the system Si₃N₄-AlN-Al₂O₃-SiO₂ with a metal: nonmetal ratio of 3/4. The extent of the β -Si₃N₄ solid solution is indicated in the behavior diagram as shown in Fig. 1. The solid solution can be described by the formula Si_{6-x}Al_xO_xN_{8-x}, where x = 0 - 4.2.

Considerable work $^{6-11}$ on stoichiometry, structure, and properties of hot pressed β -Si₃N₄ solid solution has been reported in the literature indicating that these ceramics have a combination of mechanical, thermal, and chemical properties, which might make them candidates for high-temperature structural applications in heat engines. These refractory ceramics are difficult to densify without hot pressing. However, hot pressing is a batch process and has limited shape capability. Therefore, it is usually not considered to be a cost effective process. As a result, effort is now being concentrated on the development of pressureless sintering methods to density these ceramics. Recently, Lumby et al. ¹² reported on the fabrication and properties of β -Si₃N₄ solid solution but the compositions and additives were not reported. Wills ¹³ produced high density reaction sintered β -Si₃N₄ solid solution of composition 50 mol % Si₃N₄-25 mol % AlN-25 mol % Al₂O₃. In order to obtain high final density by pressureless sintering, additives are commonly used to promote sintering. However, the additives also limit the high-temperature strength by forming a viscous grain boundary phase.

The purpose of this study was to develop high density β' -Si₃N₄ solid solutions by pressureless sintering utilizing two levels of additive, and to determine high-temperature mechanical strength, thermal shock, and oxidation resistance.

EXPERIMENTAL PROCEDURES

The compositions investigated correspond more or less to 20 Al: 80 Si/10 O:90 N (equivalent percent), as marked in the behavior diagram⁵ shown in Fig. 1. "X" phase has a detrimental effect on high-temperature strength, therefore, the target composition was selected purposely below the β -Si₃N₄ solid solution homogeneity line (Fig. 1) to prevent its formation during sintering by a shift in com-

position over the β -Si $_3\mathrm{N}_4$ solid solution line. The composition shift was anticipated to be very likely because of the presence of oxygen in the form of ${\rm SiO}_2$ in the starting materials, and further utilization of oxide additives. The basic constituents were Si₃N₄, AlN, and Al₂O₃. To them were added minor amounts of additives Y2O3-SiO2, to promote sintering. A molar ratio of 1:2 was chosen to form $Y_2Si_2O_7$ phase, which has been found to be compatible with β -Si₂N₄ solid solution, according to the phase diagram 14 shown in Fig. 2. Further, it was anticipated that the Y₂Si₂O₇ phase might improve the oxidation behavior since both Y_2O_3 and SiO_2 are in the highest state of oxidation, thus acting as a barrier for further diffusion of oxygen in the sintered material. Using the target composition 20 Al: 80 Si/10 O: 90 N (equivalent percent), two different mixtures were made with Si₃N₄, AlN, Al₂O₃, Y₂O₃, and SiO₂ powders with two levels in the Y_2O_3 -SiO $_2$ additive system. For simplicity, they are to be referred as composition A and B containing 6 mol % and 3 mol % Y_2O_3 -SiO $_2$. These are listed in Table I. The $\mathbf{Y}_2\mathbf{O}_3$ to \mathbf{SiO}_2 molar ratio was always constant at 1:2. The purpose of utilizing the additive system (Y2O3-SiO2) was to develop a process capable of yielding fully dense β '-Si $_3$ N $_4$ solid solution by pressureless sintering under a nitrogen pressure of 1 atmosphere.

Commercial grade $\mathrm{Si}_3\mathrm{N}_4$, AlN, $\mathrm{Al}_2\mathrm{O}_3$, $\mathrm{Y}_2\mathrm{O}_3$, and SiO_2 powders were used in the fabrication studies. Mixtures for 100 gram batches were well milled in polyethylene bottles for 17 to 20 hours using high alumina grinding media and ethanol. The starting compositions were adjusted to allow for pick up of alumina from the mills. The pick up varied slightly depending on the milling time and weight of the ball charge but was typically 0.8 wt % for a 200 gram ball charge (in a 100-g powder charge) milled for 17 to 20 hours.

After milling, the slurry was dried on a heated aluminum plate, and sieved through a 60-mesh sieve to break up the agglomerates. Twenty grams of mixed powder was cold formed into rectangular blocks of 7.6 by 2.5 by 0.64 cm, by die pressing followed by cold isostatic pressing of four blocks in one batch (in rubber bags) at a total pressure of 414 MN/m².

The compacts were pressureless sintered in a "cold-wall" furnace at temperatures between 1450° and 1750° C for periods of 1 to 2 hours under nitrogen pressure of 1 atmosphere. After sintering, the compacts were furnace cooled.

Sintered specimens were machined into test bars and the surfaces were subsequently ground with a 220-grit diamond wheel to a final surface roughness of 10 to 15 microinches rms. The final dimensions of the test bars were 2.54 by 0.64 by 0.32 cm with four edges beveled.

Density was measured on the machined test bars by liquid immersion and pycnometric methods. Microstructural characterization was made by optical microscopy and transmission electron microscopy, while phase identification and elemental analysis were carried out by X-ray diffraction and EDAX techniques.

Modulus of rupture tests were conducted by four point loading with 0.95 cm top and 1.87 cm bottom spans. Testing was done at room temperature, 1000°, 1200°, and 1380° C. All testing was conducted in air with a cross head velocity of 0.02 cm/min. Fracture surfaces of selected test specimens were examined in the scanning electron microscope to determine the fracture origins

For oxidation tests, the machined bars (2.54 by 0.64 by 0.32 cm) were placed in a platinum crucible. The crucible was introduced into a preheated furnace and automatically cycled. Each cycle consisted of 1 hour at 1375° C followed by 20 minutes cooling. After each 15 hours at temperature (20 hr elapsed time) had accumulated, the bars were separately weighed. The cyclic heating was continued for a total of 90 hours at temperature. Characterization of the oxide scales was performed by light microscopy and X-ray diffraction.

Thermal shock tests were conducted by holding the bars in a vertical tube furnace for 15 minutes to reach an equilibrium temperature and dropping them into a container of water at room temperature. The severity of thermal shock was adjusted by varying the temperature of the tube furnace. Strength after thermal shock was measured at room temperature in a four point bend test with a cross head speed of 0.02 cm/min.

RESULTS AND DISCUSSIONS

A. Powder Characterization

Impurity analyses of the "as-received" powders are shown in Table II, indicating that the AlN starting powder contained most of the major impurities found, that is, Fe, Si, Ti, W, Ni, while the starting powder Y_2O_3 had only Al as a major impurity. All other powders Si_3N_4 , Al_2O_3 , and SiO_2 were relatively free from such impurities. The oxygen content of the starting Si_3N_4 powder was 2.7 wt %, while the specific surface area (BET method) was $11.84 \text{ m}^2/\text{g}$ The surface areas of other starting powders were $3.40 \text{ m}^2/\text{g}$ for AlN; $14.45 \text{ m}^2/\text{g}$ for Al_2O_3 ; $5.16 \text{ m}^2/\text{g}$ for Y_2O_3 ; and $158.46 \text{ m}^2/\text{g}$ for SiO_2 .

B. Densification

Densification behavior of compositions A and B as a function of temperature is shown in Fig. 3. Very rapid densification takes place between 1550° and 1650° C. At 1700° C, maximum density of 3.08 g/cc was obtained in the composition A with 6 mol % Y_2O_3 -SiO₂ additives, while with 3 mol % additives in composition B, the density was 2.94 g/cc. These values are approximately 98 percent of theoretical for composition A and 94 percent of theoretical for composition B, on the basis of an assumed density of 3.14 g/cc for the blend of Si_3N_4 , AlN, and Al_2O_3 , 15 adjusted for the additions of Y_2O_3 and SiO_2 . Densification was facilitated by increased Y_2O_3 -SiO₂ additives. Further, the densification of these mixtures is consistent with a liquid phase sintering process, 11 , 16 and appears to be analogous to that of silicon nitride. $^{17-20}$

C. Characterization

X-ray diffraction examinations were made for phase identification in the sintered specimens. Figure 4 shows X-ray diffraction results of compositions A and B sintered at 1700° C for 1 hour. The diffraction pattern for both compositions were almost identical in every detail, and only β -Si₃N₄ solid solution was detected as a major phase. No other phases or additional peaks of significant intensities were observed. Also, no Y₂Si₂O₇ could be detected in either of the

sintered compositions. This observation is consistent with those of Rowcliffe et al. 19 and Smith, 20 who also did not find the crystalline $Y_2Si_2O_7$ phase in sintered Si_3N_4 specimens utilizing Y_2O_3 sintering aid. It is concluded that the additives Y_2O_3 -SiO $_2$ most probably formed an yttria-silica glassy phase, which became liquid at the sintering temperature and thus facilitated densification. The presence of such a noncrystalline phase although not identifiable by X-rays was deduced either from the observed deterioration of mechanical properties 21 at elevated temperatures or from the observation of presumed devitrification products after heat treatment. 22

Microstructure characterization was made by optical microscope, transmission microscope and energy dispersive X-ray analysis (EDAX) techniques. Figure 5 shows typical microstructures developed in the sintered compositions A and B. The microstructures consist of an essentially single phase β -Si₃N₄ solid solution (light gray) phase with isolated porosity (dark gray) combined with some pull outs from polishing.

The porosity was typically associated with the lower density of the sintered specimens from composition B. Several "white" particles were also identified in very limited areas and were examined in the SEM using X-ray energy dispersive spectrometer. Spectra were taken from several of these particles and the matrix. Si and Al were detected only in the matrix. Elements detected in the white metallic particles were Fe, W, Ti, Cr, and Mo, which can be attributed to the impurities present in the "as-received" AlN powder as indicated in Table II.

Further microstructural characterization was conducted on electron transparent specimens. Figures 6 and 7 show typical transmission micrographs of sintered material. Composition A with 6 mol % Y_2O_3 -SiO $_2$ additives had a mixture of equiaxed grains ranging between 0.15 to 1.2 μ m, and columnar grains of size range 0.15 μ m wide by 2.0 μ m long to 1.3 μ m wide by 5.0 μ m long (Fig. 6). By contrast, composition B containing 3 mol % additives had predominantly

equiaxed grains of size range 0.25 to 2.0 μ m (Fig. 7). Indications of a non-crystalline phase, which however, could not be identified, were present in the microstructures at the triple grain intersections. The grain morphology, in all instances, is typical of liquid phase sintering and solution reprecipitation mechanisms, that is, the silicate liquid forms the reactive transport medium in the form of a thin layer between transforming crystals. The liquid phase is retained in intercrystalline spaces, and grain boundaries, during cooling from the sintering temperature.

D. Modulus of Rupture Test

Modulus of rupture tests were conducted to evaluate the strength of the sintered β^{1} -Si₂N₄ solid solution at both room and elevated temperatures. Machined bend bars from both compositions (A and B) having density values 3.08 and 2.94 g/cc were evaluated. The variation in M O.R. strength as a function of temperature to 1380° C is plotted in Fig. 8. Each point on the curve is the average of four tests. Average strengths for composition A (6 mol % Y₂O₃-SiO₂) were 483 MPa up to a temperature of 1000° C 345 MPa at 1200° C 2nd 220 MPa at 1380° C. For composition B (3 mol % Y₂O₃-SiO₂), the average M.O.R. strength was 428 MPa at room temperature, 400 MPa at 1000° C, 324 MPa at 1200° C, and 228 MPa at 1380° C. The lower strength value for composition B at room temperature can be attributed to higher porosity than that in composition A. On the other hand, the lower strength values at 1200° and 1380° C for both compositions A and B can be attributed to the effect of additives (Y_2O_3 -SiO $_2$), which formed a grain boundary amorphous phase(s) which, in turn, became viscous at the test temperatures. This behavior is analogous to that of both sintered and hot pressed Si_3N_4 containing MgO, 21 Y_2O_3 , 17 , 18 CeO_2 , 23 ZrO_2 , 23 etc. It was anticipated, however, that a lower amount of additives or liquid phase(s) might result in greater high-temperature strength in the sintered materials. However, the present results indicated that the strength values at $1380^{\rm O}$ C are almost equivalent for composition A containing 6 mol % additives as compared to composition B containing 3 mol % additives. The exact effect of the amount of additives on the high temperature strength cannot be explained in the present study due to the fact that composition B, although containing less additives, also has lower density than that of composition A, which could counterbalance any effect of additives on improvement in strength.

Fracture surfaces of selected broken bend bars were examined to identify the origin of fractures. In most cases, the roum-temperature fractures appeared to initiate from surface or edge flaws, indicating that better surface preparation might lead to improved strengths. On the other hand, high-temperature fractures were due to slow crack growth regions, where the crack front advanced along the grain boundaries resulting in an intergranular failure which is typical of Si₃N₄ based ceramics. These are shown in Figs. 9 (composition A) and 10 (composition B). While Fig. 9(a) shows room-temperature brittle fracture, Figs. 9(b) and (c) are fracture surfaces at 1200° and 1380° C, respectively, showing the fracture initiation site (V-shaped area when the two halves joined together), which is typical of slow crack growth at high temperatures. Similar behavior was observed in the fracture surfaces of composition B, which are shown in Figs. 10(a), (b), and (c).

E. Oxidation

Oxidation tests were carried out under identical conditions for both composition A and composition B. The oxidation cycle consisted of 1 hour at temperature (1375°C) followed by 20 minutes cooling. After each 15 hours at temperature (20 hr elapsed time) had accumulated, weight gain for each bar was measured separately. Weight gain versus time for compositions A and B is linearly plotted in Fig. 11, while the parabolic plot is in Fig. 12. Composition A with 6 mol % Y_2O_3 -SiO₂ additives exhibited a higher weight gain than composition B with 3 mol % Y_2O_3 -SiO₂, that is, less oxidation resistance than composition B, although it had been anticipated initially that composition A would exhibit better oxidation resistance than composition B due to its higher Y_2O_3 -SiO₂ content. Both compositions A and B exhibited more or less parabolic rate behavior which

is shown in Fig. 12. However, in composition A, a change in the slope of the parabolic plot was observed after approximately 30 hours of oxidation time and parabolic behavior continued at the new slope for the duration of the test.

Whether this change in parabolic behavior was due to different types of reaction 24 occurring during oxidation, for example, reaction with the impurities, phase transformation or spalling was not determined.

The oxide scale in composition A was identified by X-ray to contain cristobalite as the major phase with minor amounts of mullite, while in composition B, mullite was the major phase with minor amounts of cristobalite. Further, composition A produced thick oxide wales whitish in color with a rough surface, while composition B exhibited this scales with smooth surface. These differences were attributed to the different nature of the oxidation products from composition B.

F. Thermal Shock

The water quench thermal shock test was performed on a total of 20 test bars of composition A only. After quenching from various temperatures into water at room temperature, the test bars were dried, and 4-point modulus of rupture strength was measured at room temperature on each thermally shocked bar to determine the residual strength. These values are plotted as a function of quenching temperature difference as shown in Fig. 13. Each point on the curve is the average of four tests. No strength loss was observed up to a temperature difference of 300° C, followed by a gradual strength loss in a "quasistatic" manner up to 460° C, after which the strength drop was catastrophic.

The $\triangle T$ °C was determined to be between 460° to 480° C (Fig. 13). The value was found to be higher than that of various silicon carbide ceramics, equivalent to that of reaction sintered silicon nitride but lower than hot pressed silicon nitride 26 which are shown in Fig. 13. The result suggests that the pressureless sintered β '-Si $_3$ N $_4$ solid solution possess thermal shock resistance comparable to that of materials which are currently being considered for high-temperature applications.

CONCLUDING REMARKS

The experimental studies reported here have shown that high density β^* -Si $_3$ N $_4$ solid solution can be prepared by pressureless sintering ultrafine Si $_3$ N $_4$, AlN, and Al $_2$ O $_3$ powders with an Y $_2$ O $_3$ -SiO $_2$ additive system, under relatively simple sintering conditions. Densification takes place by a liquid phase sintering mechanism involving solution of α -Si $_3$ N $_4$ and reprecipitation as β^* -Si $_3$ N $_4$. The sintered product is essentially β^* -Si $_3$ N $_4$ solid solution. No crystalline Y $_2$ Si $_2$ O $_7$ could be detected suggesting the formation of an yttriasilica glassy phase during sintering. Strengths up to 483 MPa (70 000 psi) are achieved at moderate temperature (1000°C), while a substantial strength loss occurs at high temperature (1380°C). It is believed that this problem can be overcome by better understanding of the grain boundary recrystallization process.

The oxidation resistance of a composition containing 3 mol % Y_2O_3 -SiO₂ is better than the oxidation resistance of a composition containing 6 mol % (Y_2O_3 -SiO₂). In thermal shock, β '-Si₃N₄ solid solution exhibits higher resistance than silicon carbide and resistance equivalent to reaction sintered silicon nitride but lower than hot pressed silicon nitride.

The results of strength, oxidation, and thermal shock tests at this stage in our development of β^i -Si $_3$ N $_4$ solid solution are comparable to many currently sintered silicon nitride based ceramics and are extremely encouraging; they suggest that, with further development, it will be possible to make sintered β^i -Si $_3$ N $_4$ solid solution with properties suitable for high-temperature applications.

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TABLE I. - MATERIAL COMPOSITIONS FOR β '-Si $_3$ N $_4$ SOLID SOLUTION

Material	Mol %		Wt %		
	A	В	A	В	
Si ₃ N ₄	52	54	71	73.5	
AlN	32	33	13	13.1	
Al ₂ O ₃	10	10	10	10	
Y ₂ O ₃	2	1	4	2.2	
SiO ₂	4	2	2	1.2	

TABLE II. - TRACE IMPURITY ANALYSIS OF RAW POWDERS (ppm)

Element	Si ₃ N ₄ GTE	AlN Shield alloy	Al ₂ / Lind A	SiO ₂ Apache	Y ₂ O ₃ United Mineral
Al		Major	Major	100	640
Co	50	110			
Cu		100		70	
Cr		210		50	90
Fe	70	1750	70	180	160
Mg			110	110	90
Mn		120			
Mo		290			
Ni		130			
Si	Major	400	154	Major	230
Ti		390			
v		140	 -		
w		470			
Zr		160			

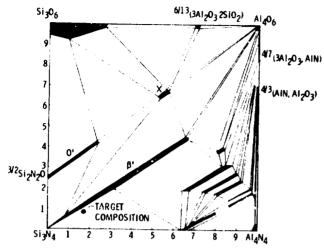


Figure 1. - The $\mathrm{Si}_3\mathrm{N}_4$ -AIN-AI $_2\mathrm{O}_3$ -SiO $_2$ system lafter Jack 5).

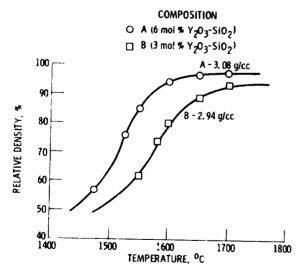


Figure 3. – Density of β' -Si₃N₄ solid solutions for 1 hour at different temperatures.

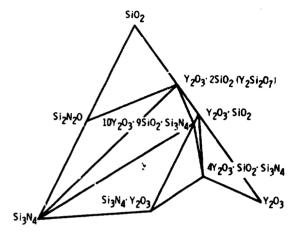


Figure 2. - The system Si_3N_4 - Y_2O_3 - SiO_2 showing solid-solid equilibriz at 1700 (after Wills 14).

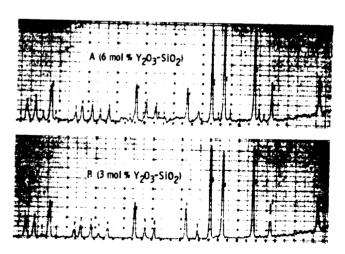
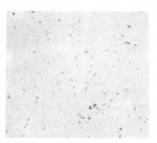


Figure 4. - X-ray d ffraction data of B'-Si₃N₄ solid solution compositions.







3.08 g/cc; A-6 mol% Y₂O₃-SiO₂

2.94 g/cc; B-3 mol% Y203-SiO2

Figure 5. – Microstructures of $\beta^{\text{\tiny{1}}}$ – Si_3N_4 solid solution compositions sintered for 1 hour at 1700 C; X250.

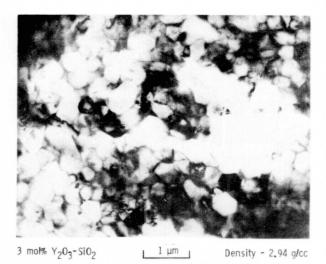
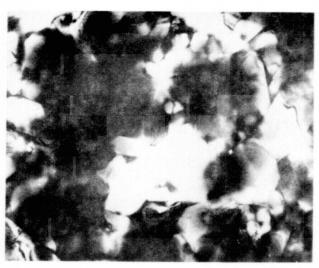


Figure 7. - Transmission electron micrograph of β^{1} - $Si_{3}N_{4}$ solid solution showing faceted grain structures.



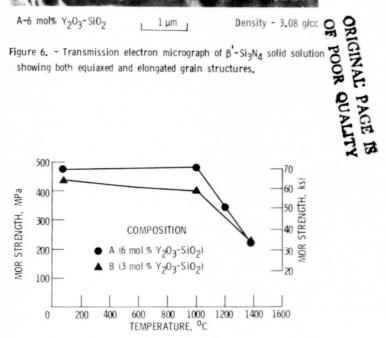


Figure 8. - Modulus of rupture strength (4-point bend) of β'-Si₃N₄ solid solutions.

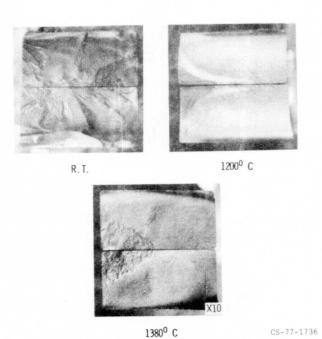


Figure 9. - Macrographs of β' - Si_3N_4 solid solution fractured at different temperatures; composition, A-6 mol% Y_2O_3 - SiO_2 ; density, 3.08 g/cc.

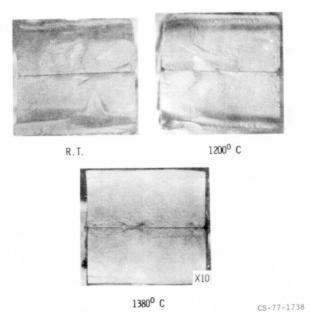


Figure 10. - Macrographs of β' - Si₃N₄ solid solution fractured at different temperatures; composition, B-3 mol% Y₂O₃-SiO₂; density, 2.94 g/cc.

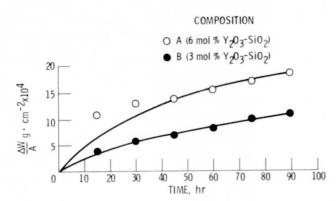


Figure 11. – Weight gain in air at 1375 $^{\circ}$ C of $\,\beta'$ –Si $_3\!N_4$ solid solutions (linear plot).

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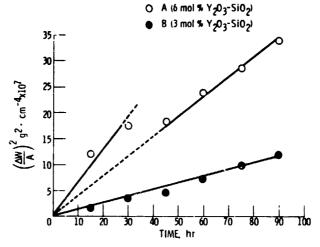


Figure 12. - Weight gain in air at 13750 C of $\,\beta'\text{-Si}_3N_4$ solid solutions (parabolic plot).

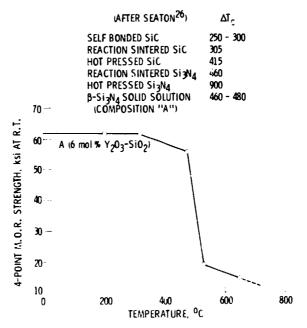


Figure 13. - Residual strength at room temperature after water quenching vs quench temperature for β' -Si $_3N_4$ solid solution (composition A).